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RF Micro Devices(R) Selected to Support Next-Generation Family of Leading Smartphones

RFMD(R) Powering Multiple Devices for Top-Tier Smartphone Manufacturer

BARCELONA, Spain, Feb. 28, 2012 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced it has been selected to support multiple next-generation devices for a leading manufacturer of 3G/4G smartphones. The next-generation devices include a highly anticipated LTE smartphone that will feature multiple variants of RFMD's family of ultra-high efficiency WCDMA and 4G LTE power amplifiers.

RFMD is currently supporting multiple devices for this top-tier smartphone manufacturer with a broad range of highperformance products, including PowerSmart[®] power platforms, ultra-high efficiency 3G/4G power amplifiers, and multiple switch-based components.

Eric Creviston, president of RFMD's Cellular Products Group, said, "RFMD continues to increase our exposure to the world's leading smartphone manufacturers. With these wins, we expand our participation in a growing family of highly popular smartphones and bolster our position in the high-growth LTE category. We look forward to expanding our content opportunity in future devices as new programs ramp and as new product families are introduced."

RFMD's ultra-high efficiency 3G and 4G LTE PAs deliver an enhanced user experience by extending battery life and reducing the thermal impact of data usage in smartphones. The product family currently covers WCDMA bands 1, 2, 3, 4, 5, and 8, and LTE bands 4, 7, 11, 13, 17, 18, 20, and 21 — addressing the most common UMTS/HSPA+ and LTE frequency bands and band combinations. Additional multimode, multi-band (MMMB) and single-mode LTE variants will be introduced in the first half of calendar 2012.

RFMD offers a broad portfolio of 3G and 4G LTE solutions in single-mode and converged architectures to ensure alignment with leading chipset providers and enable worldwide network compatibility. RFMD's 3G and 4G LTE product portfolio reduces the thermal impact of data usage in smartphones while enabling increased battery life during data-based applications, such as web surfing, video calls and internet radio services.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at <u>www.rfmd.com</u>.

The RF Micro Devices, Inc. logo is available at http://www.globenewswire.com/newsroom/prs/?pkgid=6436

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a

substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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